

General Description

The AOZ8235 is a transient voltage suppressor diode array designed to protect data lines from high transient conditions and ESD. This state-of-the-art device utilizes AOS leading edge Trench Vertical Structure [TVS]² ™ technology for superior clamping performance.

This device incorporates five TVS diodes in a single package. Due to the flexibility of the design, the package can be configured as a four channel bidirectional TVS array. During transient conditions, the TVS diodes direct the transient to ground. They may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (±15 kV air, ±8 kV contact discharge).

The AOZ8235 comes in an RoHS compliant DFN package and is rated over a -40 °C to +85 °C ambient temperature range.

The very small 1.45 mm \times 1.0 mm \times 0.55 mm DFN package makes it ideal for applications where PCB space is a premium. The small size and high ESD protection makes it ideal for protecting high speed video and data communication interfaces.

Features

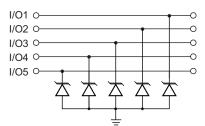
- ESD protection for high-speed data lines:
 - Exceeds: IEC 61000-4-2 (ESD) ±18 kV (air), ±18 kV (contact)
 - Human Body Model (HBM) ±30 kV
- Trench Vertical Structure [TVS]² ™ based technology used to achieve excellent ESD clamping performance
- Small package saves board space
- Low insertion loss
- Protects five unidirectional or four bidirectional I/O lines
- Low clamping voltage
- Low operating voltage: 5.0V
- Green product, Pb-free

Applications

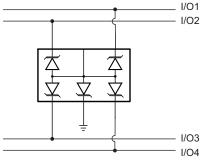
- Portable handheld devices
- Keypads, data lines
- Notebook computers
- Digital cameras
- Portable GPS
- MP3 players



Typical Applications

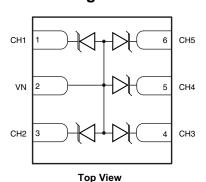


Unidirection Protection of Five Lines



Bidirection Protection of Four Lines

Pin Configuration





Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental
AOZ8235DI-05	-40 °C to +85 °C	DFN 1.45 x 1.0	Green Product RoHS Compliant



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/media/AOSGreenPolicy.pdf for additional information.

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating	
VP – VN	5 V	
Peak Pulse Current (I _{PP}), t _P = 8/20 μs	4 A	
Storage Temperature (T _S)	-65 °C to +150 °C	
ESD Rating per IEC61000-4-2, Contact ⁽¹⁾	±18 kV	
ESD Rating per IEC61000-4-2, Air ⁽¹⁾	±18 kV	
ESD Rating per Human Body Model ⁽²⁾	±30 kV	

Notes:

- 1. IEC 61000-4-2 discharge with $C_{Discharge}$ = 150 pF, $R_{Discharge}$ = 330 Ω .
- 2. Human Body Discharge per MIL-STD-883, Method 3015 $C_{Discharge}$ = 100 pF, $R_{Discharge}$ = 1.5 k Ω .

Maximum Operating Ratings

Parameter	Rating	
Junction Temperature (T _J)	-40 °C to +125 °C	

Electrical Characteristics

 $T_A = 25$ °C unless otherwise specified.

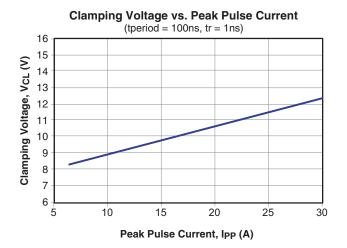
Symbol	Parameter	Conditions		Тур.	Max.	Units
V _{RWM}	Reverse Working Voltage	Between pin 5 and 2 ⁽³⁾			5.0	V
V _{BR}	Reverse Breakdown Voltage	I _T = 1 mA, between pins 5 and 2 ⁽⁴⁾	6.0			V
I _R	Reverse Leakage Current	V _{RWM} = 5 V, between pins 5 and 2			0.1	μA
V _F	Diode Forward Voltage	I _F = 15 mA	0.70	0.85	1	V
V _{CL}	Channel Clamp Voltage Positive Transients Negative Transient	I _{PP} = 15 A, tp = 100 ns, any I/O pin to Ground			12.0 -10.0	V
	Channel Clamp Voltage Positive Transients Negative Transient	I _{PP} = 25 A, tp = 100 ns, any I/O pin to Ground			15.0 -18.0	V
C _j	Junction Capacitance	V _R = 0 V, f = 1 MHz, any I/O pin to Ground		13.5	16.0	pF

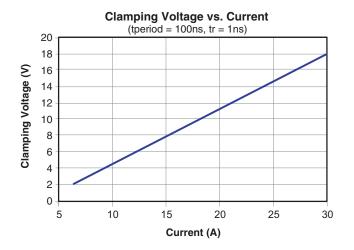
Notes

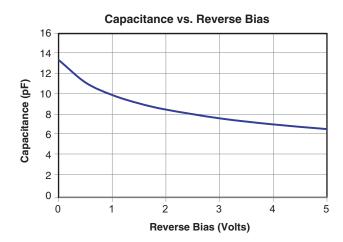
- $3. \ The \ working \ peak \ reverse \ voltage, \ V_{RWM}, \ should \ be \ equal \ to \ or \ greater \ than \ the \ DC \ or \ continuous \ peak \ operating \ voltage \ level.$
- 4. V_{BR} is measured at the pulse test current I_{T} .



Typical Performance Characteristics







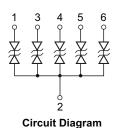


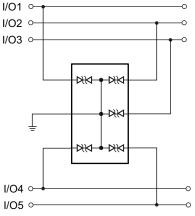
Applications Information

Device Connection for Protection of Five Unidirectional Data Lines

These devices are designed to protect up to five unidirectional data lines. The device is connected as follows.

 Unidirectional protection of five I/O lines is achieved by connecting pins 1, 3, 4, 5 and 6 to the data lines. Connect pin 2 to ground. The ground connection should be made directly to the ground plane for best results. The path length is kept as short as possible to reduce the effects of parasitic inductance in the board traces.



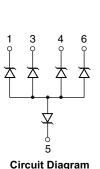


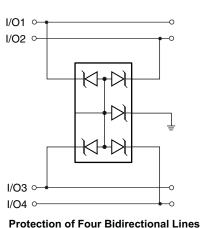
Protection of Five Unidirectional Lines

Device Connection for Protection of Four Bidirectional Data Lines

These devices are designed to protect up to four bidirectional data lines. The device is connected as follows.

 Bidirectional protection of four I/O lines is achieved by connecting pins 1, 3, 4, and 6 to the data lines. Connect pin 5 to ground. The ground connection should be made directly to the ground plane for best results. The path length is kept as short as possible to reduce the effects of parasitic inductance in the board traces.





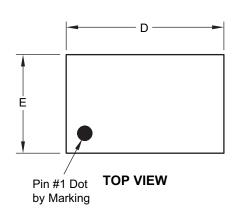
Circuit Board Layout Recommendations for Suppression of ESD

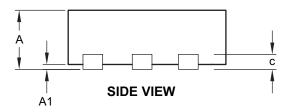
Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

- Place the TVS near the input terminals or connectors to restrict transient coupling.
- Minimize the path length between the TVS and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.

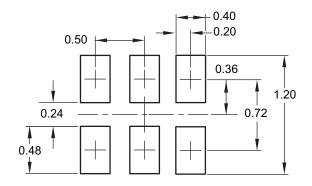


Package Dimensions, DFN 1.45 x 1.0, 6L

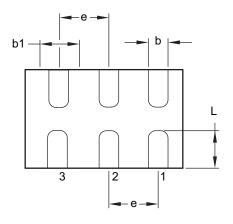




RECOMMENDED LAND PATTERN



UNIT: mm



BOTTOM VIEW

Dimensions in millimeters

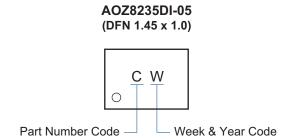
Dilliensions in minimeters					
Symbols	Min. Nom.		Max.		
Α	0.50	0.55	0.60		
A1	0.00	_	0.05		
b	0.20	0.25	0.30		
b1	0.40				
С	0.152 Ref.				
D	1.40	1.45	1.50		
E	0.95	1.00	1.05		
е	0.50 BSC				
ı	0.33	0.38	0.43		

Dimensions in inches

Symbols	Min.	Nom.	Max.
Α	0.020	0.022	0.024
A1	0.000	_	0.002
b	0.008	0.010	0.012
b1	0.016		
С	0.006 Ref.		
D	0.055	0.057	0.059
E	0.037	0.039	0.041
е	0.020 BSC		
L	0.013	0.015	0.017



Part Marking



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- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.